

3W Stereo Class-D Audio Power Amplifier and Class AB Headphone Driver (DC Volume Control, UVP, AGC)

Features

- **Operating Voltage: 3.3V-5.8V**
- **High Efficiency 85% at $P_o=3W$, 4W Speaker, $V_{DD}=5V$, AGC Disable**
- **Filter-Free Class-D Amplifier**
- **Low Shutdown Current**
 - $I_{DD}=1mA$ at $V_{DD}=5V$
- **64 Steps Volume Adjustable from -80dB to +20dB by DC Voltage with Hysteresis**
- **AGC (Non-Clip) Function**
 - Disable : 0.45VDD~VDD, Floating
 - Max, Power : Internal set limit level
- **AGC $\leq 0.27VDD$**
- **Smooth mute activation deactivation**
- **UVP Function**
 - Disable : Floating
- **Output Power at THD+N=1% BTL Mode**
 - 2.4W at $V_{DD}=5V$, $R_L=4W$
 - 1.4W at $V_{DD}=5V$, $R_L=8W$
- **SE Mode**
 - 70mW at $V_{DD}=5V$, $R_L=32W$
- **Output Power at THD+N=10%**
 - 3W at $V_{DD}=5V$, $R_L=4W$
 - 1.7W at $V_{DD}=5V$, $R_L=8W$
- **Less External Components Required**
- **Two Output Modes Allowable with BTL and SE Modes Selected by SE/BTL Pin**
- **Input Signal and Headphone Output Signal in Phase**
- **Thermal and Over-Current Protections with Auto-Recovery**
- **Power Enhanced Packages SSOP-24(236mil), QFN4x4-20A**
- **Lead Free and Green Devices Available (RoHS Compliant)**

General Description

The APA2604C is a stereo, high efficiency, filter-free Class-D audio amplifier available in a SSOP-24 and QFN4x4-20A packages.

The APA2604C provide the precise DC volume control, the gain range is from +20dB ($V_{VOLUME}=0V$) to -80dB ($V_{VOLUME}=5V$) with 64 steps precise control. It's easy to get the suitable amplifier's gain with the 64 steps gain setting. The filter-free architecture eliminates the output filters compared to the traditional Class-D audio amplifier, and reduces the external component counts and the components high, it could save the PCB space, system cost, simplifies the design and the power loss at filter.

APA2604C provides an AGC (Non-Clip) function, and this function can low down the dynamic range for large input signal. APA2604C can provide from 20dB to -80dB with 64 steps gain decrease for non-clipping function, and this function can avoid output signal clipping.

The APA2604C also integrates the de-pop circuitry that reduces the pops and click noises during power on/off or shutdown enable process.

The APA2604C has built-in over-current and thermal protection that prevent the chip being destroyed by short circuit or over temperature situation.

APA2604C combines a stereo bridge-tied loads (BTL) mode for speaker drive and a stereo single-end (SE) mode for headphone drive into a single chip, where both modes are easily switched by the SE/BTL input control pin signal.

APA2604C is capable of driving 3W at 5V into 4Ω speaker. The efficiency can archived 85% at $R_L=4\Omega$ when $P_o=3W$ at $V_{DD}=5V$.

APA2604C is capable of driving 70mW at 5V into 32Ω Headphone.

Smooth mute function when activation or deactivation mute mode to minimize pop noise.

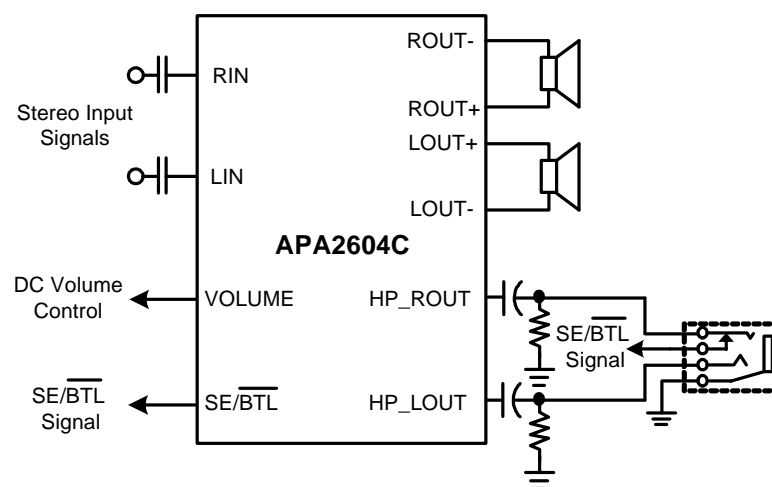
UVP function minimize power off induced pop noise.

ANPEC reserves the right to make changes to improve reliability or manufacturability without notice, and advise customers to obtain the latest version of relevant information to verify before placing orders.

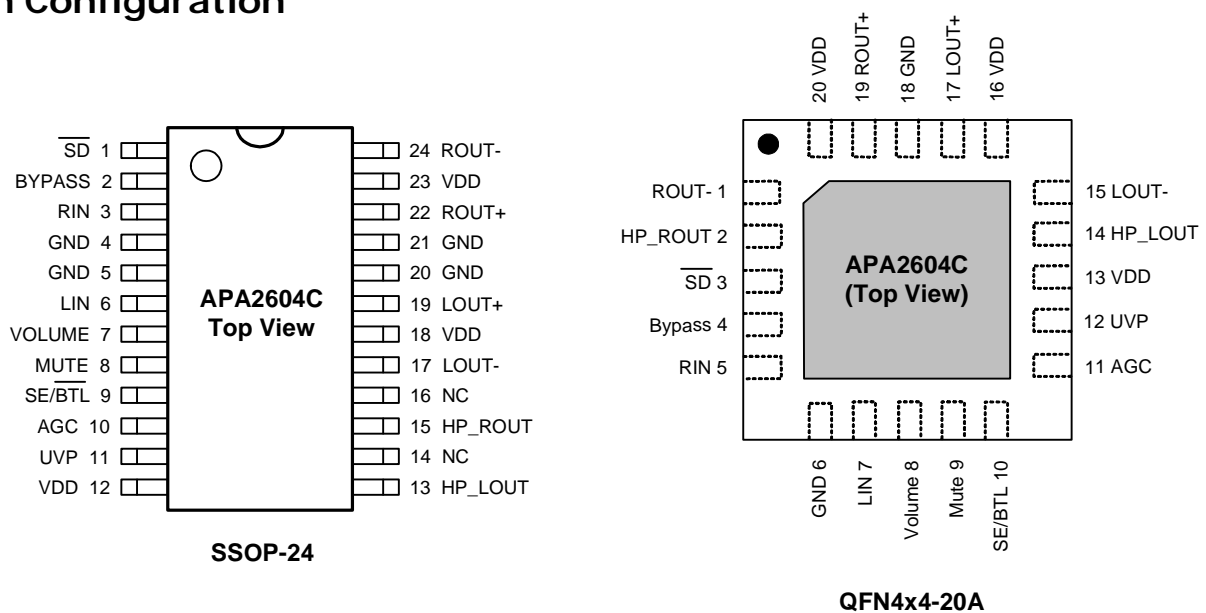
Applications

- LCD TVs
- DVD Player
- Active Speakers

Simplified Application Circuit



Pin Configuration



Recommended Operating Conditions

Symbol	Parameter		Range	Unit
V_{DD}	Supply Voltage		3.3 ~ 5.8	V
V_{IH}	High Level Threshold Voltage	\overline{SD} , MUTE	2 ~ V_{DD}	
		SE/ \overline{BTL}	0.8 V_{DD} ~ V_{DD}	
V_{IL}	Low Level Threshold Voltage	\overline{SD} , MUTE	0~0.8	
		SE/BTL	0~1.0	
V_{ICM}	Common Mode Input Voltage		1 ~ V_{DD} -1	V
T_A	Ambient Temperature Range		-40 ~ 85	°C
T_J	Junction Temperature Range		-40 ~ 125	
R_L	Speaker Resistance		3.5 ~	Ω

Electrical Characteristics

$V_{DD}=5V$, $V_{GND}=0V$, $T_A=25^\circ C$ (unless otherwise noted)

Symbol	Parameter	Test Conditions	APA2604C			Unit	
			Min.	Typ.	Max.		
I _{DD}	Supply Current (BTL)	V _{MUTE} =0V, V _{SD} =5V, No Load	-	8	20	mA	
I _{DD}	Supply Current (SE)	V _{MUTE} =0V, V _{SD} =5V, No Load	-	2	5	mA	
I _{MUTE}	Supply Current (BTL)(MUTE)	V _{MUTE} =5V, V _{SD} =5V, No Load	-	8	20	mA	
I _{MUTE}	Supply Current (SE)(MUTE)	V _{MUTE} =5V, V _{SD} =5V, No Load	-	2	5	mA	
I _{SD}	Supply Current	V _{MUTE} =0V, V _{SD} =0V, No Load	-	-	1	μA	
I _i	Input Current	SD, MUTE, VOLUME	-	-	1		
F _{OSC}	Oscillator Frequency	(V _{DD} =3.3~5.5V, T _A =-40~85°C)	400	500	600	kHz	
R _i	Input Resistance (BTL)	Gain=20dB	-	36	-	kΩ	
R _i	Input Resistance (SE)	Gain=3.5dB	-	59	-	kΩ	
R _{DS(ON)}	Static Drain-Source On-State Resistance	V _{DD} =5.5V, I _L =0.8A	P-channel Power MOSFET	-	250	-	mΩ
			N-channel Power MOSFET	-	250	-	
		V _{DD} =4.5V, I _L =0.6A	P-channel Power MOSFET	-	270	-	
			N-channel Power MOSFET	-	270	-	
		V _{DD} =3.6V, I _L =0.4A	P-channel Power MOSFET	-	300	-	
			N-channel Power MOSFET	-	300	-	
T _{START-UP}	Start-Up Time from Shutdown	Bypass Capacitor, C _B =2.2μF.	-	1.4	-	s	
V _{UVP}	External undervoltage detection		1.18	1.25	1.32	V	
I _{Hys}	External undervoltage detection hystereis current		3.76	4.7	5.64	μA	

Electrical Characteristics (Cont.)

$V_{DD}=5V$, $V_{GND}=0V$, $T_A=25^{\circ}C$, Gain=20dB (unless otherwise noted)

Operating Characteristics, BTL Mode

Symbol	Parameter	Test Conditions		APA2604C			Unit
				Min.	Typ.	Max.	
V _{DD} =5V, T _A =25°C, GAIN=20dB							
P _O	Output Pow er	THD+N=1% f _{in} =1kHz	R _L =4Ω	2.2	2.4	-	W
			R _L =8Ω	1.0	1.4	-	
		THD+N=10% f _{in} =1kHz	R _L =4Ω	-	3	-	
			R _L =8Ω	-	1.7	-	
η	Efficiency	R _L =4Ω, P _O =3W		-	85	-	%
THD+N	Total Harmonic Distortion Plus Noise	f _{in} =1kHz	R _L =4Ω, P _O =1.7W	-	0.1	0.3	
			R _L =8Ω, P _O =1W	-	0.08	0.2	
Crosstalk	Channel Separation	P _O =0.2W, R _L =4Ω, f _{in} =1kHz		-	-95	-80	dB
PSRR	Pow er Supply Rejection Ratio	R _L =4Ω, Input AC-Ground	f _{in} =100Hz	-	-80	-	
			f _{in} =1kHz	-	-80	-	
SNR	Signal to Noise Ratio	With A-w eighting Filter V _O =1V _{rms} , R _L =8Ω		-	-92	-	
Att _{Mute}	Mute Attenuation	f _{in} =1kHz, R _L =8Ω, V _{in} =1V _{rms}		-	-100	-	
Att _{shutdown}	Shutdow n Attenuation	f _{in} =1kHz, R _L =8Ω, V _{in} =1V _{rms}		-	-120	-	
V _n	Output Noise in Mute	With A-w eighting Filter (Gain=20dB)		-	50	-	μVrms
V _{OS}	Output Offset Voltage	R _L =4Ω (Gain=20dB)		-	5	30	mV
V _{DD} =3.6V, T _A =25°C, GAIN=20dB							
P _O	Output Pow er	THD+N=1% f _{in} =1kHz	R _L =4Ω	-	1.25	-	W
			R _L =8Ω	0.6	0.7	-	
		THD+N=10% f _{in} =1kHz	R _L =4Ω	-	1.55	-	
			R _L =8Ω	-	0.85	-	
η	Efficiency	R _L =4Ω, P _O =1.4W		-	83	-	%
THD+N	Total Harmonic Distortion Plus Noise	f _{in} =1kHz	R _L =4Ω, P _O =0.8W	-	0.2	0.3	
			R _L =8Ω, P _O =0.5W	-	0.1	0.3	
Crosstalk	Channel Separation	P _O =0.1W, R _L =4Ω, f _{in} =1kHz		-	-95	-80	dB
PSRR	Pow er Supply Rejection Ratio	R _L =4Ω, Input AC-Ground	f _{in} =100Hz	-	-80	-	
			f _{in} =1kHz	-	-80	-	
SNR	Signal to Noise Ratio	With A-w eighting Filter V _O =1V _{rms} , R _L =8Ω		-	-92	-	
Att _{Mute}	Mute Attenuation	f _{in} =1kHz, R _L =8Ω, V _{in} =1V _{rms}		-	-100	-	
Att _{shutdown}	Shutdow n Attenuation	f _{in} =1kHz, R _L =8Ω, V _{in} =1V _{rms}		-	-120	-	
V _n	Output Noise in Mute	With A-w eighting Filter (Gain=20dB)		-	50	-	μVrms
V _{OS}	Output Offset Voltage	R _L =4Ω, (Gain=20dB)		-	5	30	mV

Electrical Characteristics (Cont.)

$V_{DD}=5V$, $V_{GND}=0V$, $T_A=25^{\circ}C$, Gain=3.5dB (unless otherwise noted)

Operating Characteristics, SE mode

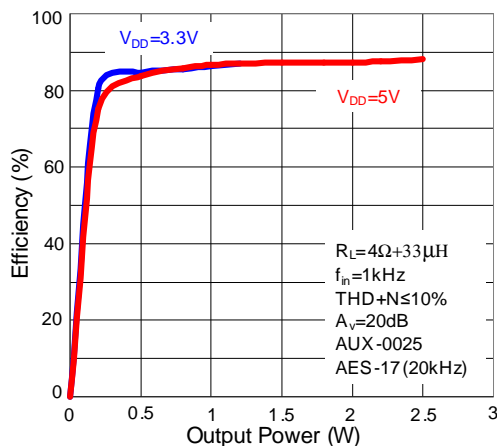
Symbol	Parameter	Test Conditions		APA2604C			Unit
				Min.	Typ.	Max.	
V _{DD} =5V, T _A =25°C, GAIN=3.5dB							
P _O	Output Power	THD+N=1% f _{in} =1kHz	R _L =32Ω	60	70	-	mW
		THD+N=10% f _{in} =1kHz	R _L =32Ω	-	90	-	
THD+N	Total Harmonic Distortion Plus Noise	f _{in} =1kHz	R _L =32Ω P _O =42.5mW	-	0.015	-	%
Crosstalk	Channel separation	P _O =6mW, R _L =32Ω, f _{in} =1kHz		-	-96	-80	dB
PSRR	Power Supply Rejection Ratio	R _L =32Ω, Input AC-Ground	f _{in} =100Hz	-	-70	-	
			f _{in} =1kHz	-	-75	-	
SNR	Signal to Noise Ratio	With A-weighting Filter V _O =1V _{rms} , R _L =32Ω		-	-100	-	
Att _{Mute}	Mute Attenuation	f _{in} =1kHz, R _L =32Ω, V _{in} =1V _{rms}		-	-100	-	
Att _{shutdown}	Shutdown Attenuation	f _{in} =1kHz, R _L =32Ω, V _{in} =1V _{rms}		-	-100	-	
V _n	Output Noise in Mute	With A-weighting Filter (Gain=3.5dB)		-	10	-	μVrms

Pin Description

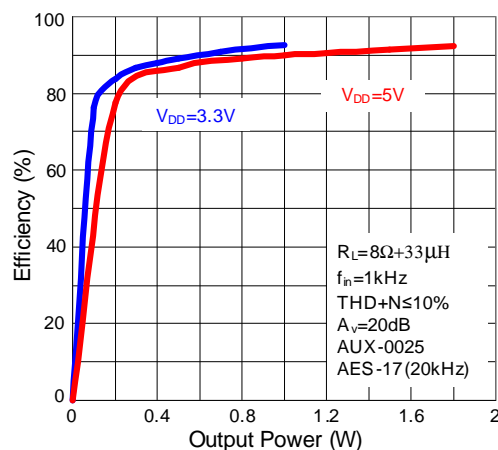
NO.		Name	Function Description
SSOP-24	QFN-20		
1	3	\overline{SD}	Shutdown mode control input. Pulling low the voltage on this pin shuts off the IC.
2	4	BYPASS	Bias voltage for power amplifiers.
3	5	RIN	Negative input of right channel power amplifier.
4,5,20,21	6,18	GND	Power amplifier's ground.
6	7	LIN	Negative input of left channel power amplifier.
7	8	VOLUME	Internal gain setting input.
8	9	MUTE	Mute control signal input, hold low for normal operation, hold high to mute.
9	10	SE/BTL	Output mode control input, high for SE output mode and low for BTL mode.
14,16	-	NC	No connection.
10	11	AGC	Maximum output power setting input.
11	12	UVP	Under voltage protection input.
12,18,23	13,16,20	VDD	Control and bias block's power supply.
13	14	HP_LOUT	Headphone output of left channel power amplifier.
15	2	HP_ROUT	Headphone output of right channel power amplifier.
17	15	LOUT-	Negative output of left channel power amplifier.
19	17	LOUT+	Positive output of left channel power amplifier.
22	19	ROUT+	Positive output of right channel power amplifier.
24	1	ROUT-	Negative output of right channel power amplifier.

Typical Operating Characteristics

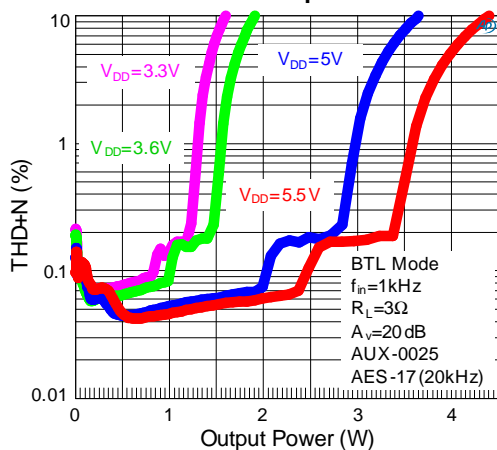
Efficiency vs. Output Power (4W)



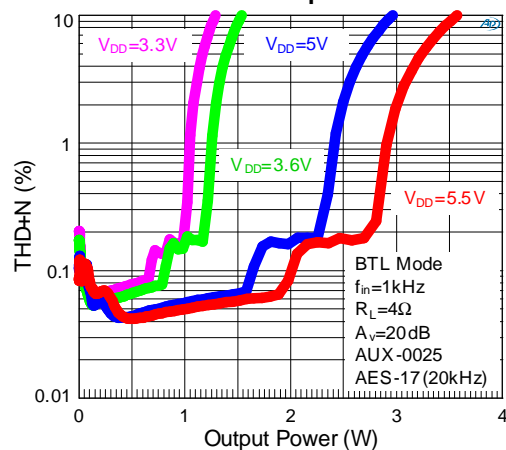
Efficiency vs. Output Power (8W)



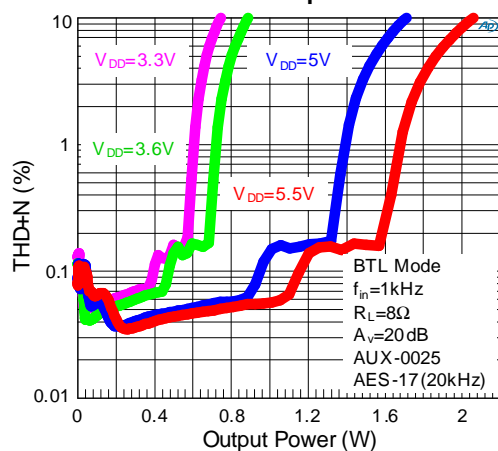
THD+N vs. Output Power



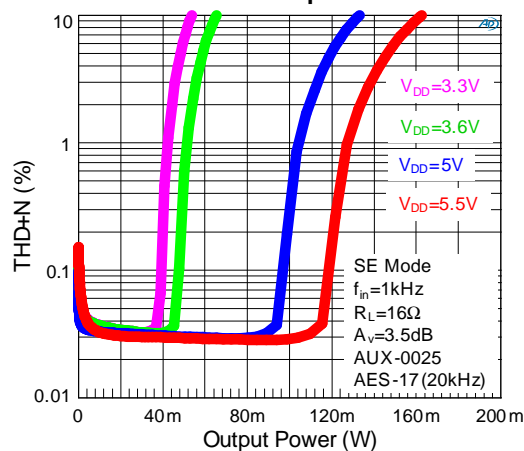
THD+N vs. Output Power



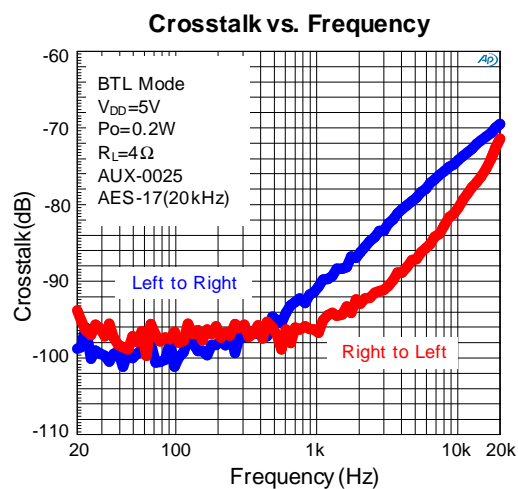
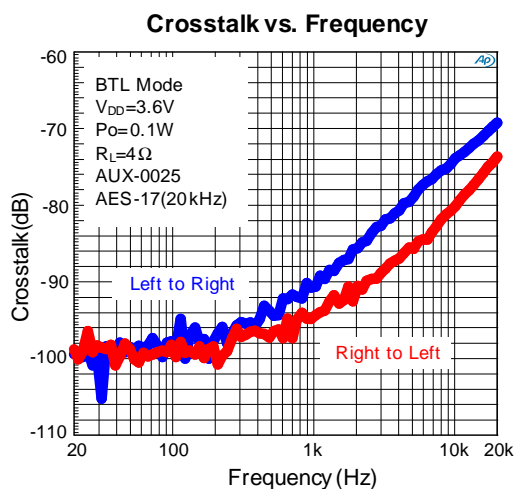
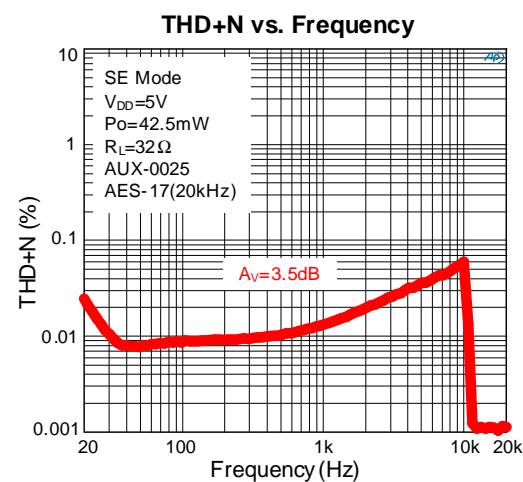
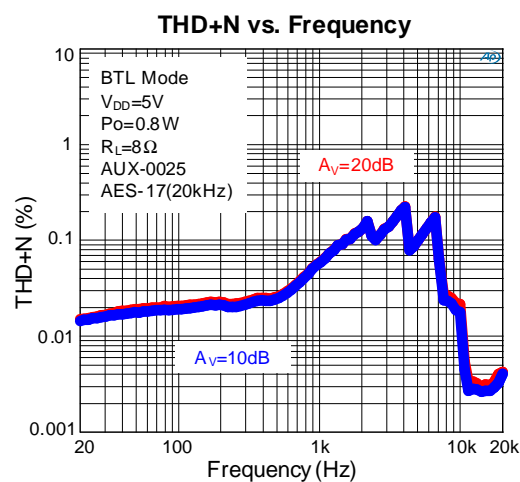
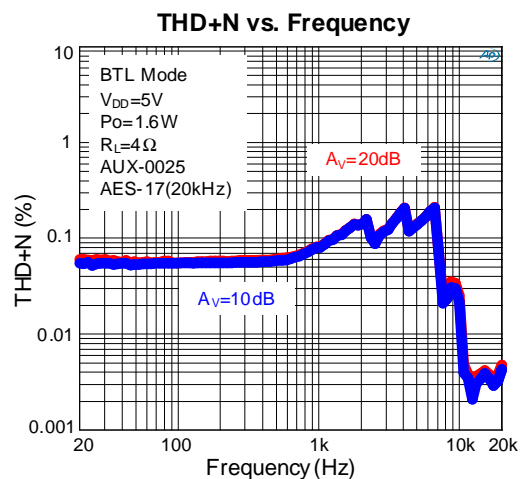
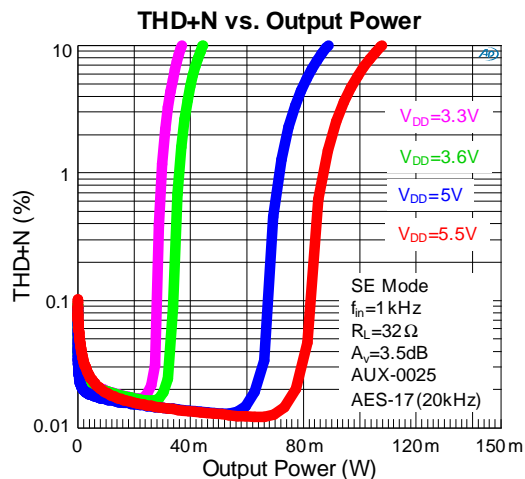
THD+N vs. Output Power



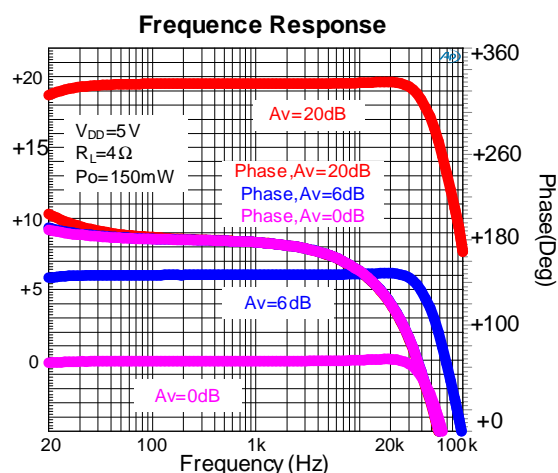
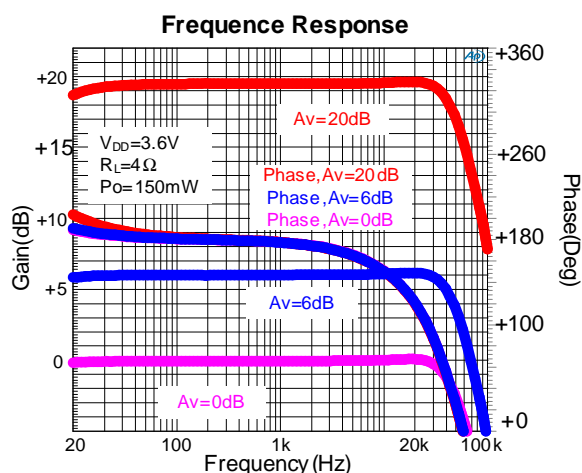
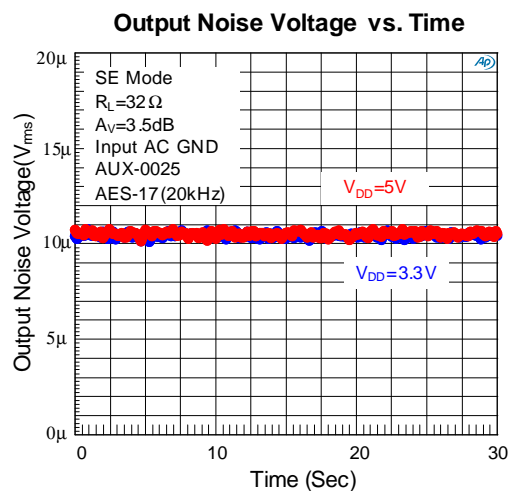
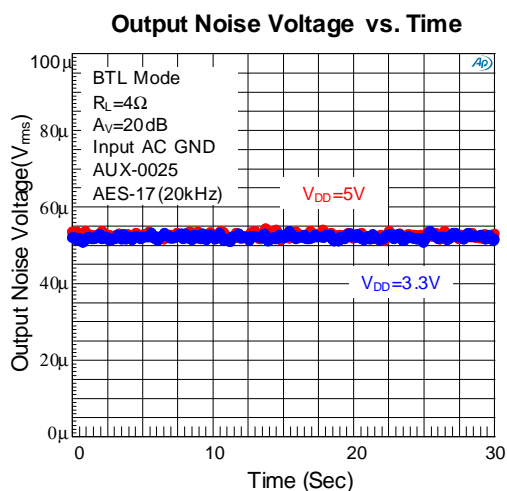
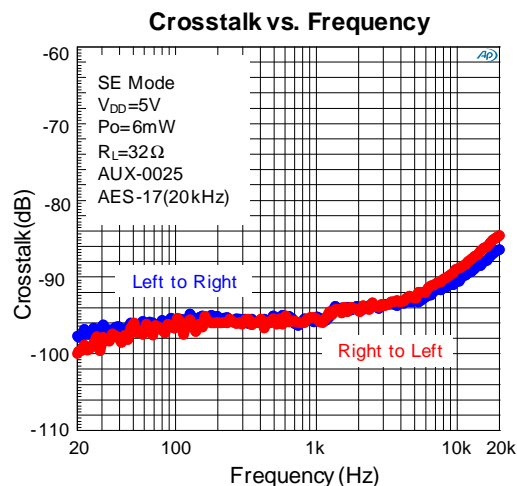
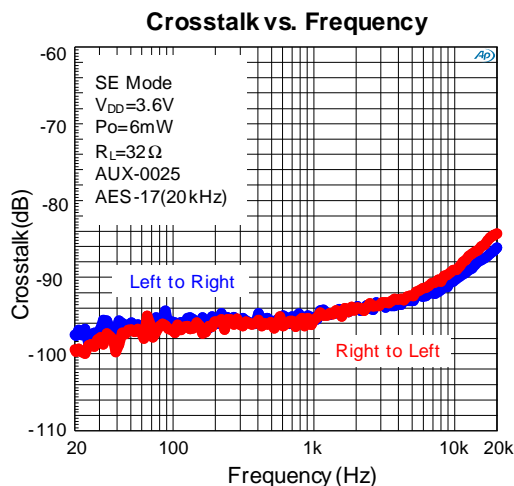
THD+N vs. Output Power



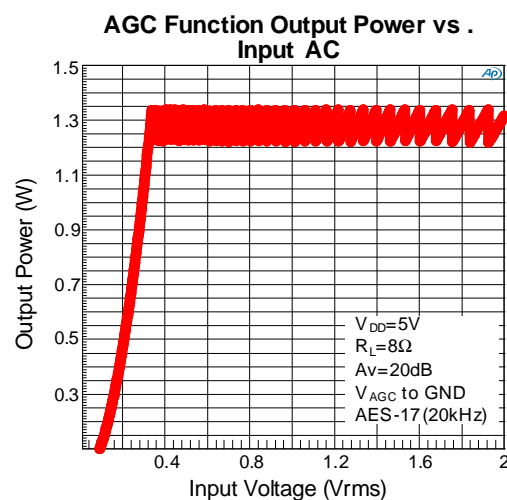
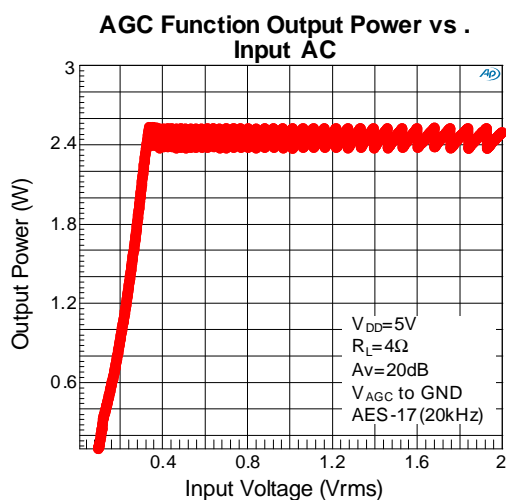
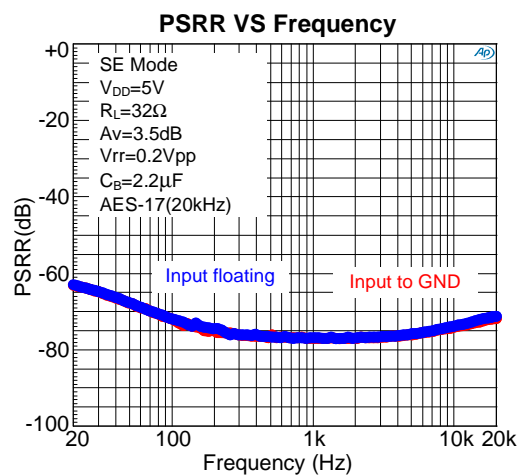
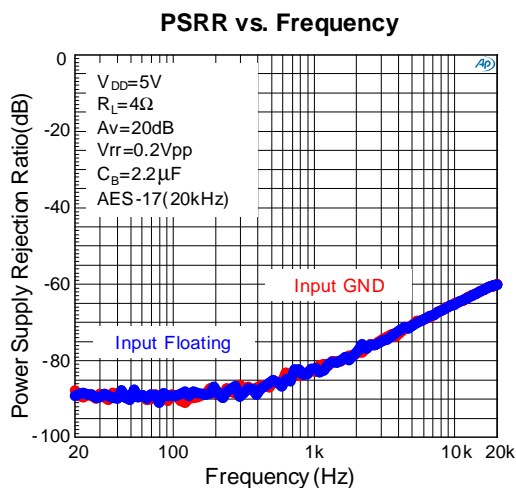
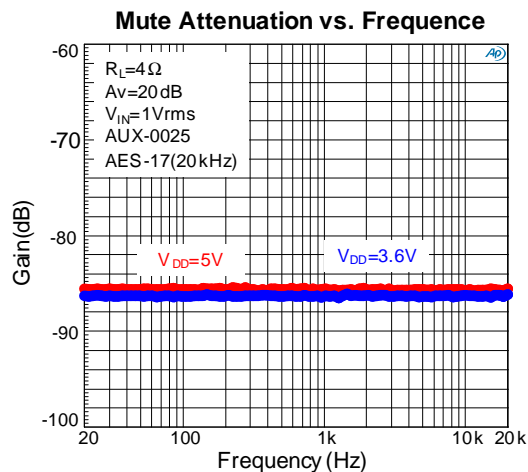
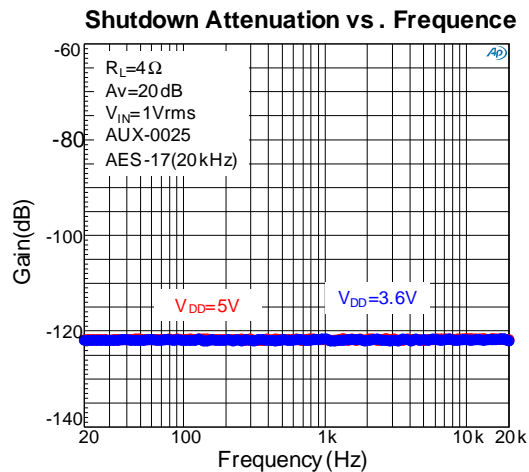
Typical Operating Characteristics



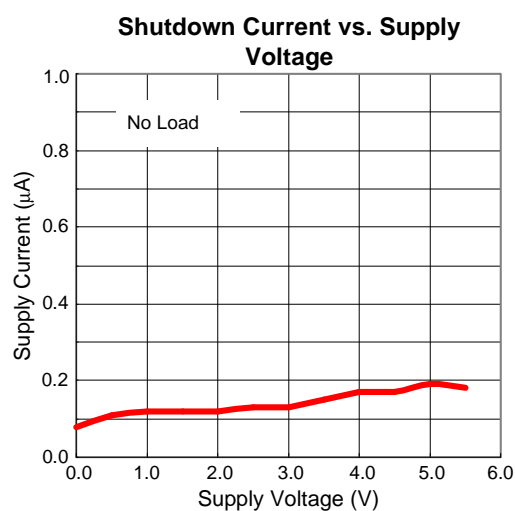
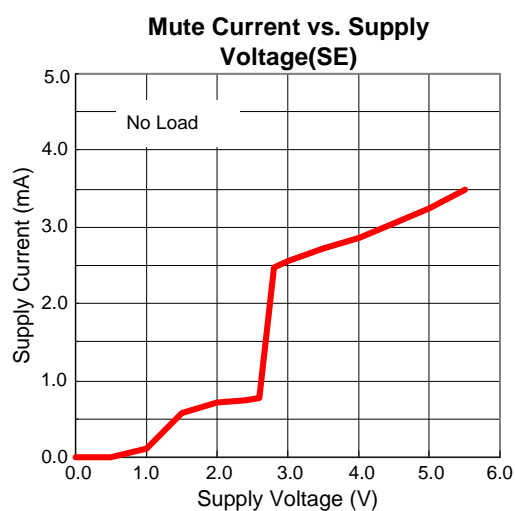
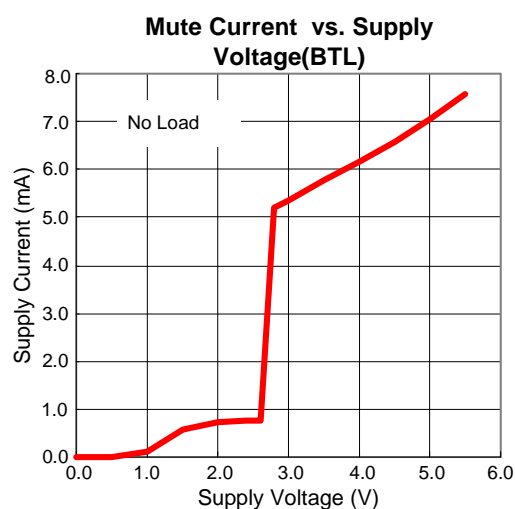
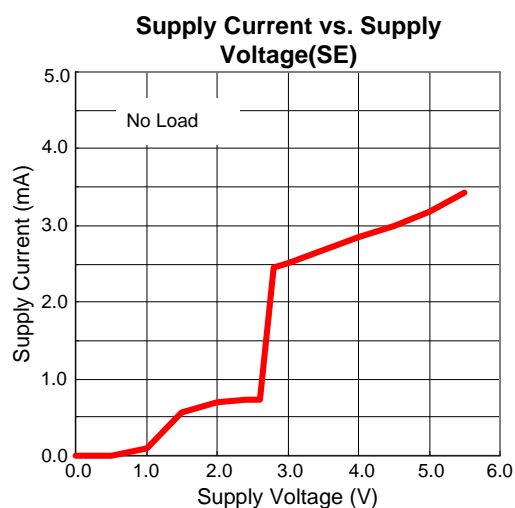
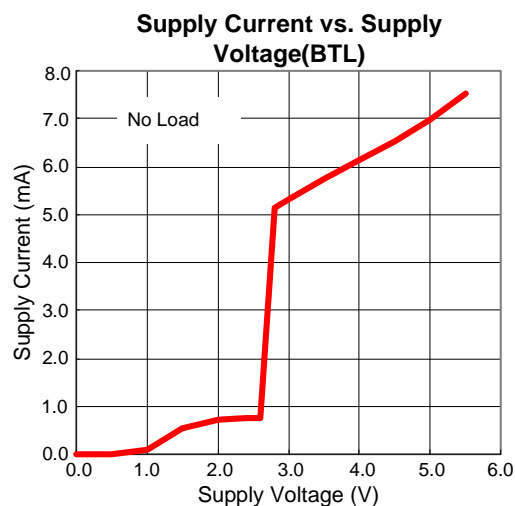
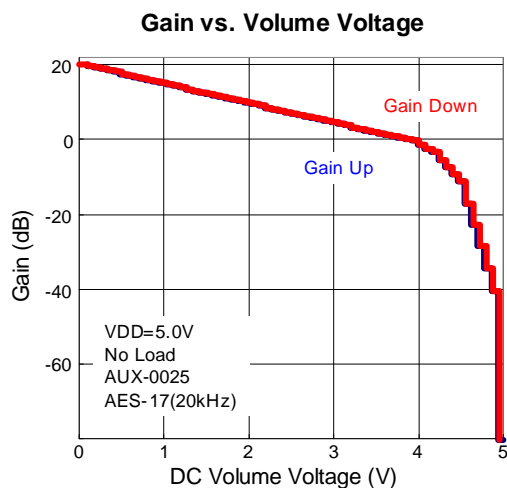
Typical Operating Characteristics



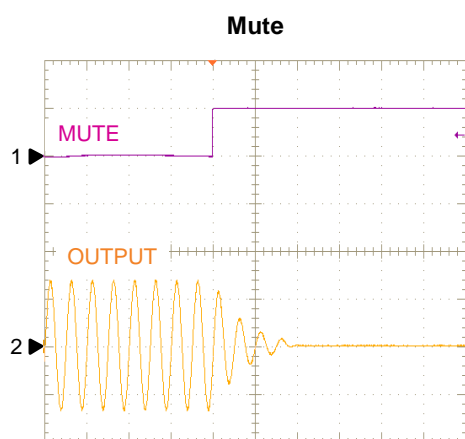
Typical Operating Characteristics



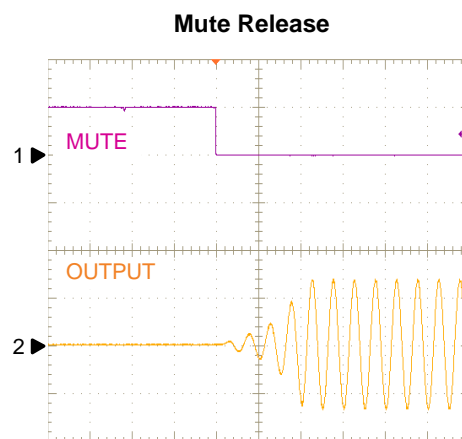
Typical Operating Characteristics



Operating Waveforms

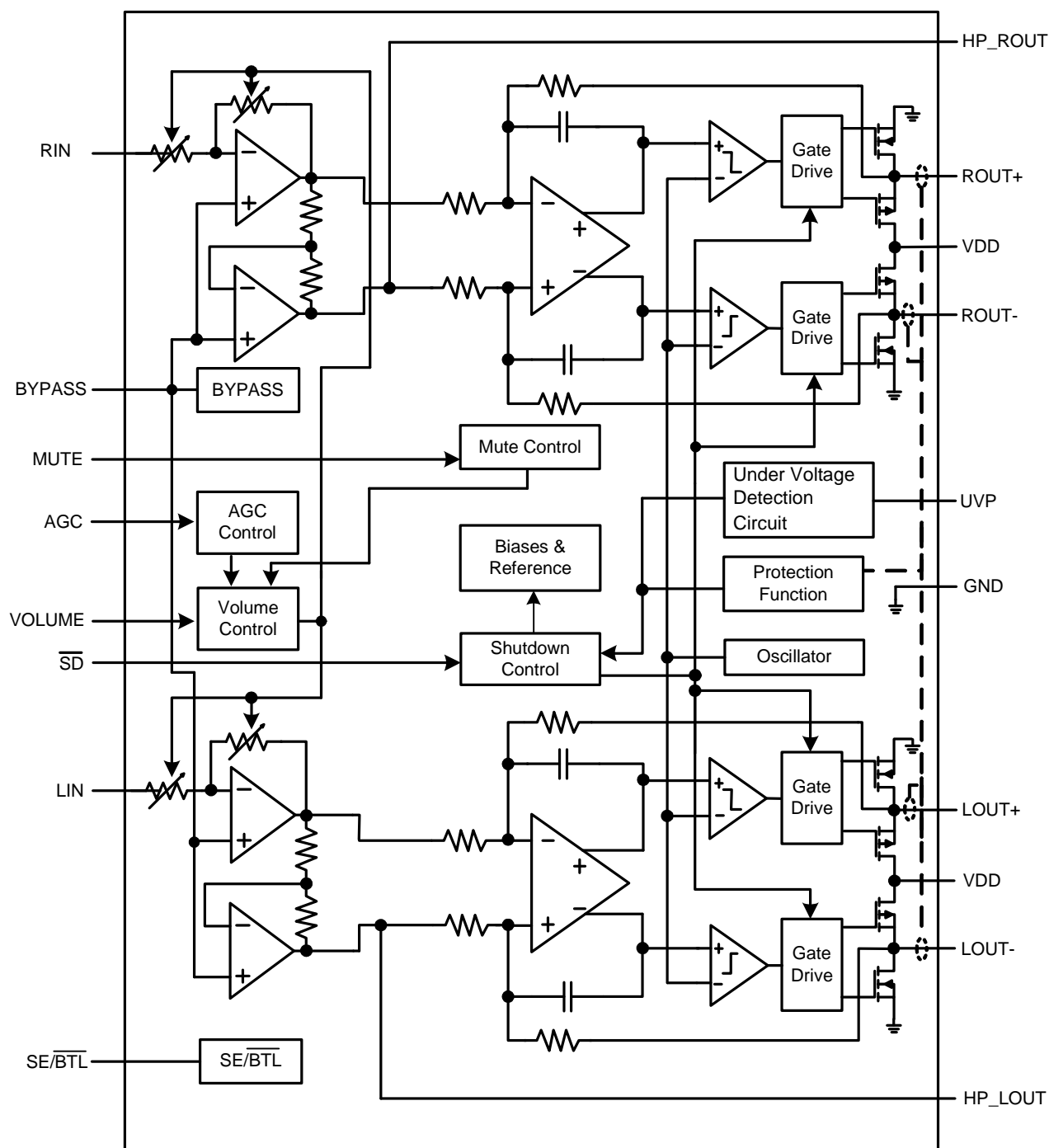


CH1:MUTE,5V/Div, DC
CH2:OUTPUT,2V/Div, DC
TIME:2mS/Div

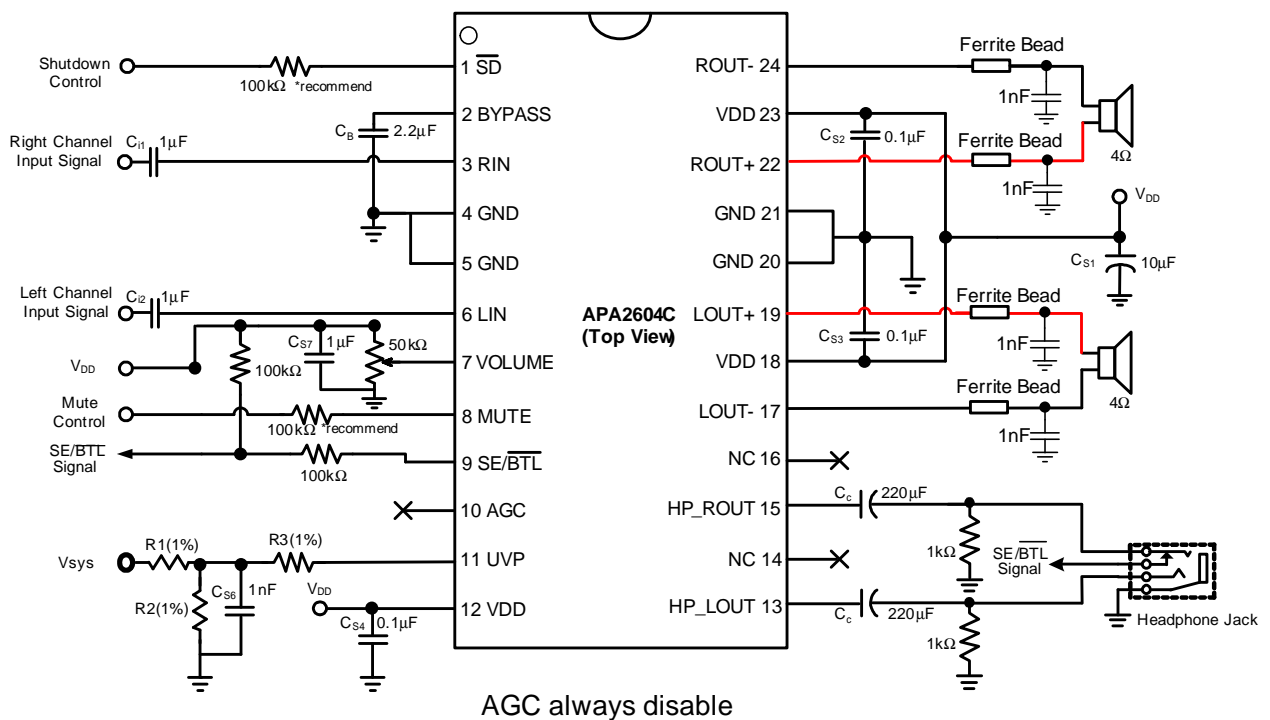
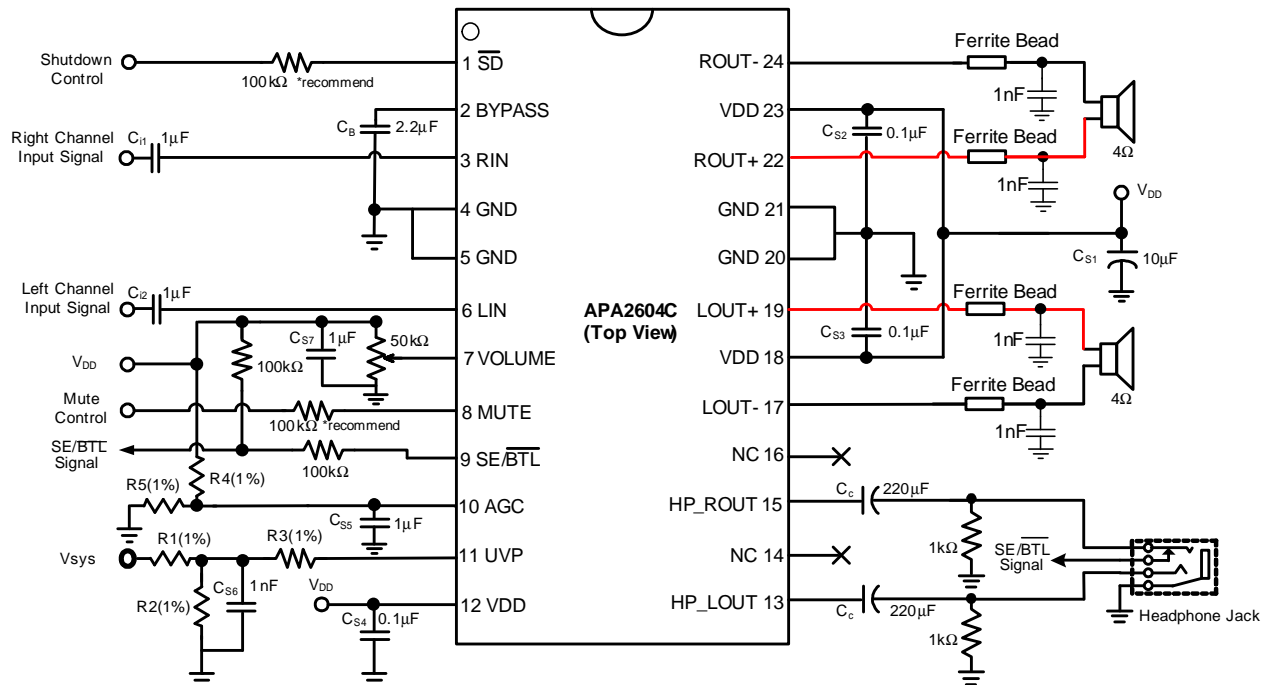


CH1:MUTE,5V/Div, DC
CH2:OUTPUT,2V/Div, DC
TIME:2mS/Div

Block Diagram



Typical Application Circuit



DC Volume Control Table

$V_{DD}=5V$, $V_{GND}=0V$, $T_A = 25^{\circ}C$, No Load

Step	BTL Gain(dB)	SE Gain(dB)	Down (%)	Down (V)	Up (%)	Up (V)	Recom(%)	Recom (V)
			Volume H to L		Volume L to H			
1	20.0	3.5	1.70	0.09	0.00	0.00	0.00	0.00
2	19.6	3.2	3.25	0.16	2.20	0.11	2.73	0.14
3	19.2	2.9	4.80	0.24	3.75	0.19	4.28	0.21
4	18.8	2.6	6.35	0.32	5.30	0.27	5.83	0.29
5	18.4	2.3	7.90	0.40	6.85	0.34	7.38	0.37
6	18.0	1.7	9.45	0.47	8.40	0.42	8.93	0.45
7	17.6	1.4	11.00	0.55	9.95	0.50	10.48	0.52
8	17.2	1.1	12.55	0.63	11.50	0.58	12.03	0.60
9	16.8	0.8	14.10	0.71	13.05	0.65	13.58	0.68
10	16.4	0.5	15.65	0.78	14.60	0.73	15.13	0.76
11	16.0	0.2	17.20	0.86	16.15	0.81	16.68	0.83
12	15.6	-0.2	18.75	0.94	17.70	0.89	18.23	0.91
13	15.2	-0.5	20.30	1.02	19.25	0.96	19.78	0.99
14	14.8	-0.8	21.85	1.09	20.80	1.04	21.33	1.07
15	14.4	-1.2	23.40	1.17	22.35	1.12	22.88	1.14
16	14.0	-1.5	24.95	1.25	23.90	1.20	24.43	1.22
17	13.6	-1.5	26.50	1.33	25.45	1.27	25.98	1.30
18	13.2	-1.8	28.05	1.40	27.00	1.35	27.53	1.38
19	12.8	-2.2	29.60	1.48	28.55	1.43	29.08	1.45
20	12.4	-2.5	31.15	1.56	30.10	1.51	30.63	1.53
21	12.0	-2.9	32.70	1.64	31.65	1.58	32.18	1.61
22	11.6	-3.2	34.25	1.71	33.20	1.66	33.73	1.69
23	11.2	-3.6	35.80	1.79	34.75	1.74	35.28	1.76
24	10.8	-3.9	37.35	1.87	36.30	1.82	36.83	1.84
25	10.4	-4.3	38.90	1.95	37.85	1.89	38.38	1.92
26	10.0	-4.6	40.45	2.02	39.40	1.97	39.93	2.00
27	9.6	-5.0	42.00	2.10	40.95	2.05	41.48	2.07
28	9.2	-5.4	43.55	2.18	42.50	2.13	43.03	2.15
29	8.8	-5.7	45.10	2.26	44.05	2.20	44.58	2.23
30	8.4	-6.1	46.65	2.33	45.60	2.28	46.13	2.31
31	8.0	-6.4	48.20	2.41	47.15	2.36	47.68	2.38
32	7.6	-6.8	49.75	2.49	48.70	2.44	49.23	2.46

DC Volume Control Table (Cont.)

$V_{DD}=5V$, $V_{GND}=0V$, $T_A = 25^{\circ}C$, No Load

Step	BTL Gain(dB)	SE Gain(dB)	Down (%)	Down (V)	Up (%)	Up (V)	Recom(%)	Recom (V)
			Volume H to L		Volume L to H			
33	7.2	-7.2	51.30	2.57	50.25	2.51	50.78	2.54
34	6.8	-7.5	52.85	2.64	51.80	2.59	52.33	2.62
35	6.4	-7.9	54.40	2.72	53.35	2.67	53.88	2.69
36	6.0	-8.3	55.95	2.80	54.90	2.75	55.43	2.77
37	5.6	-8.6	57.50	2.88	56.45	2.82	56.98	2.85
38	5.2	-9	59.05	2.95	58.00	2.90	58.53	2.93
39	4.8	-9.4	60.60	3.03	59.55	2.98	60.08	3.00
40	4.4	-9.8	62.15	3.11	61.10	3.06	61.63	3.08
41	4.0	-10.1	63.70	3.19	62.65	3.13	63.18	3.16
42	3.6	-10.5	65.25	3.26	64.20	3.21	64.73	3.24
43	3.2	-10.9	66.80	3.34	65.75	3.29	66.28	3.31
44	2.8	-11.3	68.35	3.42	67.30	3.37	67.83	3.39
45	2.4	-11.6	69.90	3.50	68.85	3.44	69.38	3.47
46	2.0	-12	71.45	3.57	70.40	3.52	70.93	3.55
47	1.6	-12.4	73.00	3.65	71.95	3.60	72.47	3.62
48	1.2	-12.8	74.55	3.73	73.50	3.68	74.02	3.70
49	0.8	-13.1	76.10	3.81	75.05	3.75	75.57	3.78
50	0.4	-13.5	77.65	3.88	76.60	3.83	77.12	3.86
51	0.0	-13.9	79.20	3.96	78.15	3.91	78.67	3.93
52	-1.0	-14.9	80.75	4.04	79.70	3.99	80.22	4.01
53	-2.0	-15.8	82.30	4.12	81.25	4.06	81.77	4.09
54	-3.0	-16.8	83.85	4.19	82.80	4.14	83.32	4.17
55	-5.0	-18.8	85.40	4.27	84.35	4.22	84.87	4.24
56	-7.0	-20.7	86.95	4.35	85.90	4.30	86.42	4.32
57	-9.0	-22.7	88.50	4.43	87.45	4.37	87.97	4.40
58	-11.0	-24.7	90.05	4.50	89.00	4.45	89.52	4.48
59	-17.0	-30.7	91.60	4.58	90.55	4.53	91.07	4.55
60	-23.0	-36.9	93.15	4.66	92.10	4.61	92.62	4.63
61	-29.0	-43	94.70	4.74	93.65	4.68	94.17	4.71
62	-35.0	-49.3	96.25	4.81	95.20	4.76	95.72	4.79
63	-41.0	-55.3	97.80	4.89	96.75	4.84	97.27	4.86
64	-80.0	-80	100.00	5.00	98.30	4.92	100.00	5.00

Function Description

Class-D Operation

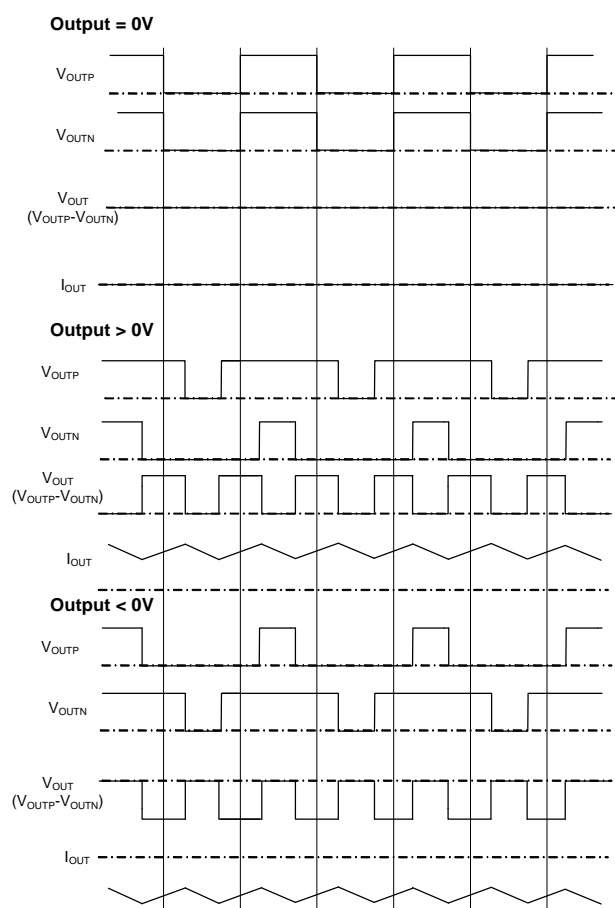
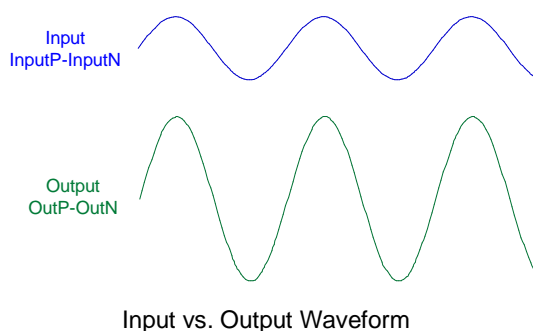


Figure1. The APA2604C Output Waveform
(Voltage & Current)



Input vs. Output Waveform

The APA2604C power amplifier modulation scheme is shown in figure 1; the outputs V_{OUTP} and V_{OUTN} are in phase with each other when no input signals. When output $> 0V$, the duty cycle of V_{OUTP} is greater than 50% and V_{OUTN} is less than 50%; when Output $< 0V$, the duty cycle of V_{OUTP} is less than 50% and V_{OUTN} is greater than 50%. This method reduces the switching current across the load, and reduces the I^2R losses in the load that improve the amplifier's efficiency.

This modulation scheme has very short pulses across the load, this making the small ripple current and very little loss on the load, and the LC filter can be eliminated in most applications. Added the LC filter can increase the efficiency by filter the ripple current.

Bypass Voltage

The bypass voltage is equal to $V_{DD}/2$, this voltage is for bias the internal preamplifier stages. The external capacitor for this reference (C_B) is a critical component and serves several important functions.

DC Volume Control Function

The APA2604C has an internal stereo volume control whose setting is the function of the DC voltage applied to the VOLUME input pin. The APA2604C volume control consists of 64 steps that are individually selected by a variable DC voltage level on the VOLUME control pin. The range of the steps controlled by the DC voltage, are from +20dB to -80dB. Each gain step corresponds to a specific input voltage range, as shown in the table. To minimize the effect of noise on the volume control pin, which can affect the selected gain level, hysteresis and clock delay are implemented. The amount of hysteresis corresponds to half of the step width, as shown in the "DC Volume Control Graph".

For the highest accuracy, the voltage shown in the "recommended voltage" column of the table is used to select a desired gain. This recommended voltage is exactly half-way between the two nearest transitions. The gains level have are 0.4dB/step from 20dB to 0dB; 1dB/step from 0dB to -3dB; 2dB/step from -3dB to -11dB and 6dB/step from -11dB to -41dB and the last step at -80dB as mute mode.

Function Description(Cont.)

AGC (Non-Clipping) Function

The APA2604C provides the 64 steps non-clipping control, and the range is from 20dB to -80dB. When the output reaches the maximum power setting value, the internal Programmable Gain Amplifier (PGA) will decrease the gain for prevent the output waveform clipping. This feature prevents speaker damage from occurring clipping. Using the AGC pin to set the non-clipping function and limit the output power.

Table 1: AGC Setting Threshold v.s Output Power

AGC Function	Output Power
VDD~0.45VDD or AGC Floating	Disable AGC Function
0.45VDD~0.27VDD	$P_o = \frac{8(\frac{1}{2}V_{DD} - V_{AGC})^2}{R_L} \times 0.95$
0.27VDD~GND	(Max Output Power 4Ω) $P_o=2.5W$ (Max Output Power 8Ω) $P_o=1.35W$

MUTE Operation

When place the logic high on MUTE pin, the APA2604C's outputs runs at a constant 50% duty cycle, and the APA2604C is at mute state. Place the logic low on MUTE pin enables the outputs, and the output changes the duty cycle with the input signal. This pin could be used as a quick disable/enable of outputs when changing channels on a television or transitioning between different audio sources. The MUTE pin must not be floating.

Smooth mute function when activation or deactivation mute mode to minimize pop noise.

Shutdown Operation

In order to reduce power consumption while not in use, the APA2604C contains a shutdown function to externally turn off the amplifier bias circuitry. This shutdown feature turns the amplifier off when logic low is placed on the \overline{SD} pin for APA2604C. It is best to switch between ground and the supply voltage VDD. By switching the \overline{SD} pin to GND level, the amplifier enters a low-consumption-current state. On normal operating, APA2604C's \overline{SD} pin should pull to VDD level to keeping the IC out of the shutdown mode. The \overline{SD} pin should be tied to a definite voltage to avoid unwanted state changes.

Over-Current Protection

The APA2604C monitors the output current, and when the current exceeds the current-limit threshold, the APA2604C turn-off the output stage to prevent the output device from damages in over-current or short-circuit condition. The IC will turn-on the output buffer after 200ms, but if the over-current or short-circuits condition is still remain, it enters the Over-Current protection again. The situation will circulate until the over-current or short-circuits has be removed.

Thermal Protection

The over-temperature circuit limits the junction temperature of the APA2604C. When the junction temperature exceeds $T_j=+170^{\circ}C$, a thermal sensor turns off the output buffer, allowing the devices to cool. The thermal sensor allows the amplifier to start-up after the junction temperature down about $140^{\circ}C$. The thermal protection is designed with a $30^{\circ}C$ hysteresis to lower the average T_j during continuous thermal overload conditions, increasing lifetime of the IC.

Under-Voltage Protection

External under voltage detection can be used to Shut-down the APA2604C before an input device can generate a pop. The shutdown threshold at the UVP pin is 1.25V. The user selects a resistor divider to obtain the shutdown threshold and hysteresis for the specific application. The thresholds can be determined as below:

With the condition: $R_3 \gg R_1 // R_2$

$$V_{UVP} = [1.25 - (I_{Hys} + initial) \times R_3] \times (R_1 + R_2) / R_2$$

$$Hysteresis = I_{Hys} \times R_3 \times (R_1 + R_2) / R_2$$

$$I_{Hys} = 4.7\mu A (typ)$$

$$initial = 1.3\mu A (typ)$$

For example, to obtain $V_{UVP}=3.8V$ and 1V hysteresis, $R_1=3k\Omega$, $R_2=1k\Omega$ and $R_3=50k\Omega$. Only if external voltage V_{system} is lower than the shutdown threshold V_{UVP} , the APA2604C is in shutdown mode. On the other hand, V_{system} could be pulled higher than V_{Hys} ($V_{UVP} + hysteresis=4.8V$) to keep the IC out of shutdown mode.

Function Description (Cont.)

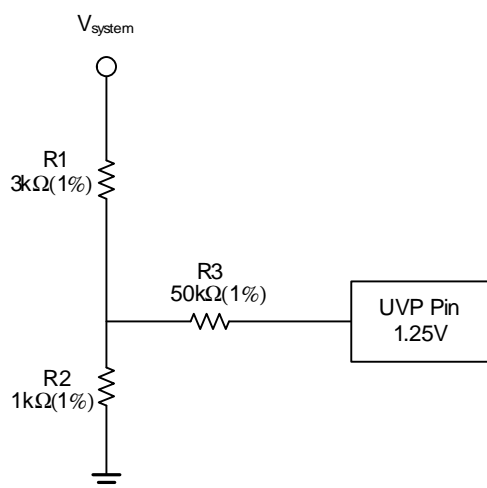


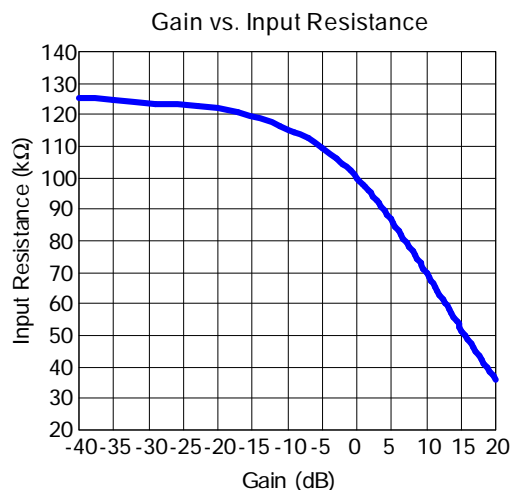
Figure 2. Under-Voltage Protection

Application Information

Square Wave into the Speaker

Apply the square wave into the speaker may cause the voice coil of speaker jumping out the air gap and defacing the voice coil. However, this depends on the amplitude of square wave is high enough and the bandwidth of speaker is higher than the square wave's frequency. For 500kHz switching frequency, this is not issued for the speaker because the frequency is beyond the audio band and can't significantly move the voice coil, as cone movement is proportional to $1/f^2$ for frequency out of audio band.

Input Resistor, R_i



For achieving the 64 steps gain setting, it varies the input resistance network (R_i & R_f) of amplifier. The input resistor's range from smallest to maximum is about 3.5 times. Therefore, the input high-pass filter's low cutoff frequency will change 3.5 times from low to high. The cutoff frequency can be calculated by equation 1.

Input Capacitor, C_i

In the typical application, an input capacitor, C_i , is required to allow the amplifier to bias the input signal to the proper DC level for optimum operation. In this case, C_i and the input impedance R_i form a high-pass filter with the corner frequency determined in the following equation:

$$f_{C(\text{highpass})} = \frac{1}{2\pi R_i C_i} \quad (1)$$

The value of C_i must be considered carefully because it directly affects the low frequency performance of the circuit. Where R_i is $36k\Omega$ (minimum) and the specification calls for a flat bass response down to 50Hz. The equation is reconfigured as below:

$$C_i = \frac{1}{2\pi R_i f_c} \quad (2)$$

When the input resistance variation is considered, the C_i is $0.08\mu F$, so a value in the range of $0.01\mu F$ to $0.022\mu F$ would be chosen. A further consideration for this capacitor is the leakage path from the input source through the input network ($R_i + R_f, C_i$) to the load. This leakage current creates a DC offset voltage at the input to the amplifier that reduces useful headroom, especially in high gain applications. For this reason, a low-leakage tantalum or ceramic capacitor is the best choice. When polarized capacitors are used, the positive side of the capacitor should face the amplifiers' input in most applications because the DC level of the amplifiers' inputs are held at $V_{DD}/2$. Please note that it is important to confirm the capacitor polarity in the application.

Effective Bypass Capacitor, C_B

As with any power amplifier, proper supply bypassing is critical for low noise performance and high power supply rejection.

The bypass capacitance affects the startup time. It is determined in the following equation:

$$T_{\text{START-UP}} = 0.56(\text{sec}/\mu F) \times C_B + 0.2(\text{sec}) \quad (3)$$

The capacitor location on the bypass pin should be as close to the device as possible. The effect of a larger half bypass capacitor is improved PSRR due to increased half-supply stability. The selection of bypass capacitors, especially C_B , is thus dependent upon desired PSRR requirements, click and pop performance. To avoid the start-up pop noise occurred, choose C_i which is not larger than C_B .

Application Information (Cont.)

Ferrite Bead Selection

If the traces from APA2604C to speaker are short, the ferrite bead filters can reduce the high frequency radiated to meet the FCC & CE required.

A ferrite that has very low impedance at low frequencies and high impedance at high frequencies (above 1 MHz) is recommended.

Output Low-Pass Filter

If the traces from APA2604C to speaker are short, it doesn't require output filter for FCC & CE standard.

A ferrite bead may be needed if it's failing the test for FCC or CE tested without the LC filter. The figure 2 is the sample for added ferrite bead; the ferrite shows choosing high impedance in high frequency.

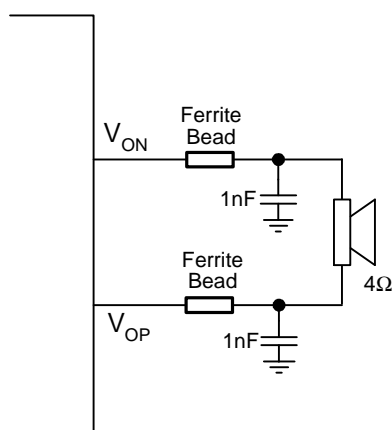


Figure 2. Ferrite bead output filter

Figure 3 and 4 are examples for added the LC filter (Butterworth), it's recommended for the situation that the trace from amplifier to speaker is too long and needs to eliminate the radiated emission or EMI.

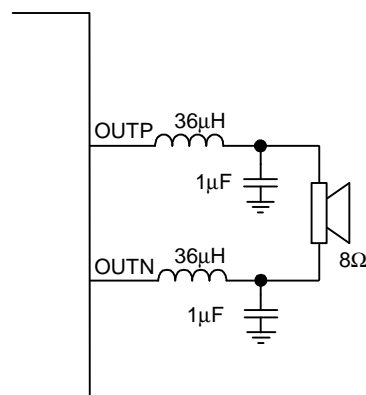


Figure 3. LC output filter for 8Ω speaker

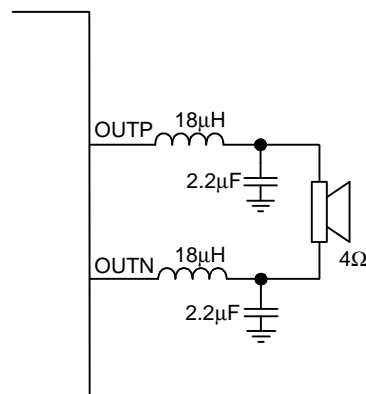


Figure 4. LC output filter for 4Ω speaker

Figure 3 and 4's low pass filter cut-off frequency are 25kHz (F_c).

$$f_{C(\text{lowpass})} = \frac{1}{2\pi\sqrt{LC}} \quad (5)$$

Power-Supply Decoupling Capacitor, C_s

The APA2604C is a high-performance CMOS audio amplifier that requires adequate power supply decoupling to ensure the output total harmonic distortion (THD) is as low as possible. Power supply decoupling also prevents the oscillations being caused by long lead length between the amplifier and the speaker.

Application Information (Cont.)

Power-Supply Decoupling Capacitor, C_s (Cont.)

The optimum decoupling is achieved by using two different types of capacitors that target on different types of noise on the power supply leads. For higher frequency transients, spikes, or digital hash on the line, a good low equivalent-series-resistance (ESR) ceramic capacitor, typically $0.1\mu\text{F}$ placed as close as possible to the device VDD pin for works best. For filtering lower frequency noise signals, a large aluminum electrolytic capacitor of $10\mu\text{F}$ or greater placed near the audio power amplifier is recommended.

Layout Recommendation

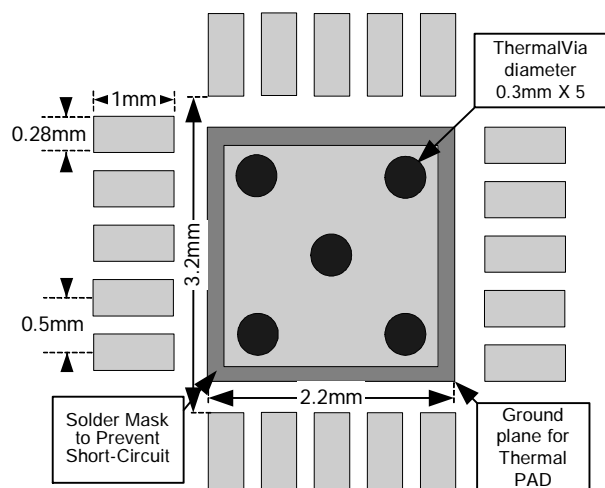


Figure 5. QFN4x4-20A Land Pattern Recommendation

1. All components should be placed close to the APA2604C. For example, the input capacitor (C_i) should be close to APA2604C's input pins to avoid causing noise coupling to APA2604C's high impedance inputs; the decoupling capacitor (C_s) should be placed by the APA2604C's power pin to decouple the power rail noise.
2. The output traces should be short, wide ($>50\text{mil}$), and symmetric.
3. The input trace should be short and symmetric.
4. The power trace width should greater than 50mil.
5. The QFN4X4-20A Thermal PAD should be soldered on PCB, and the ground plane needs soldered mask (to avoid short-circuit) except the Thermal PAD area.

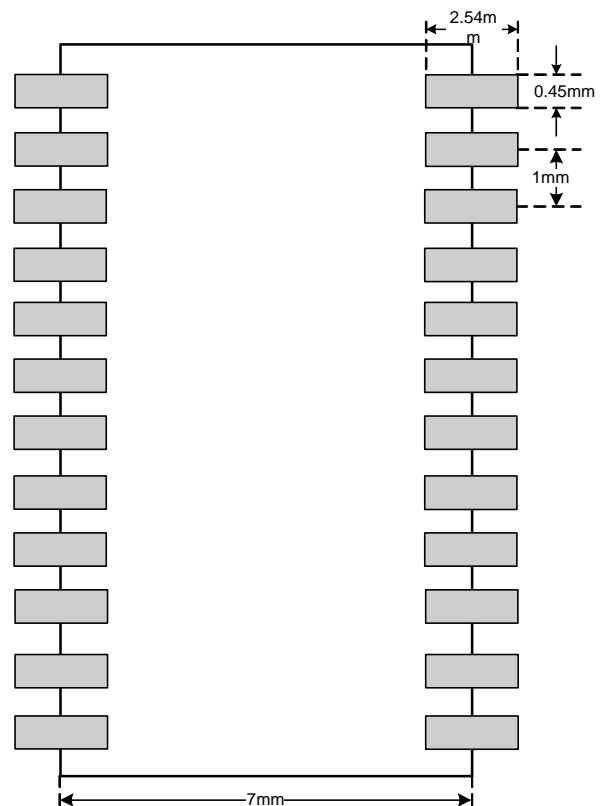
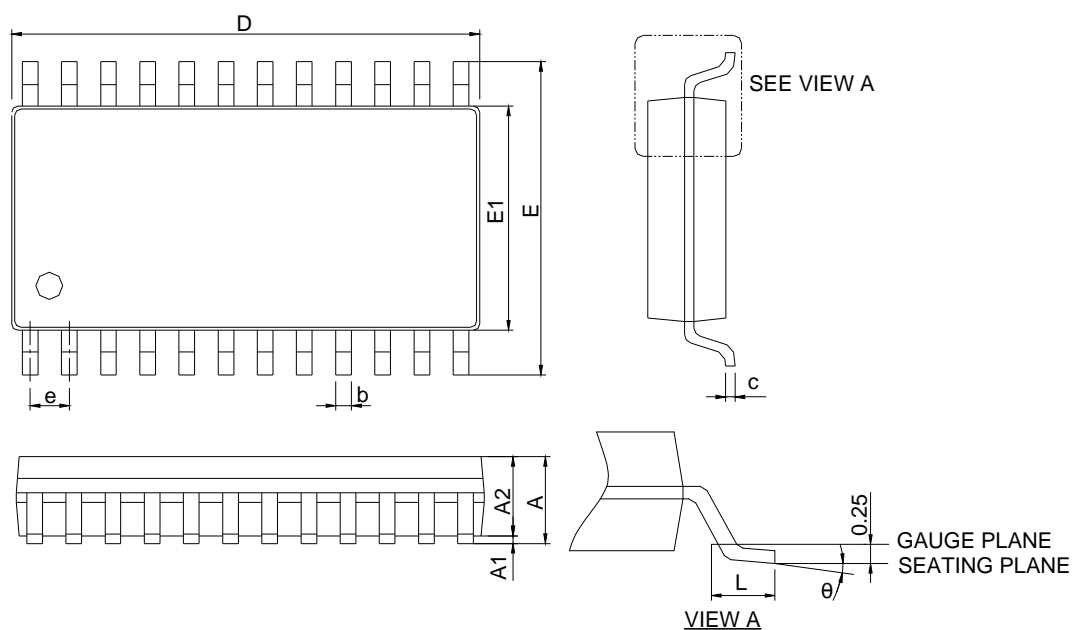


Figure 5. SSOP-24(236mil) Land Pattern Recommendation

1. All components should be placed close to the APA2604C. For example, the input capacitor (C_i) should be close to APA2604C input pins to avoid causing noise coupling to APA2604C high impedance inputs; the decoupling capacitor (C_s) should be placed by the APA2604C power pin to decouple the power rail noise.
2. The output traces should be short, wide ($>50\text{mil}$) and symmetric.
3. The input trace should be short and symmetric.
4. The power trace width should greater than 50mil.

Package Information

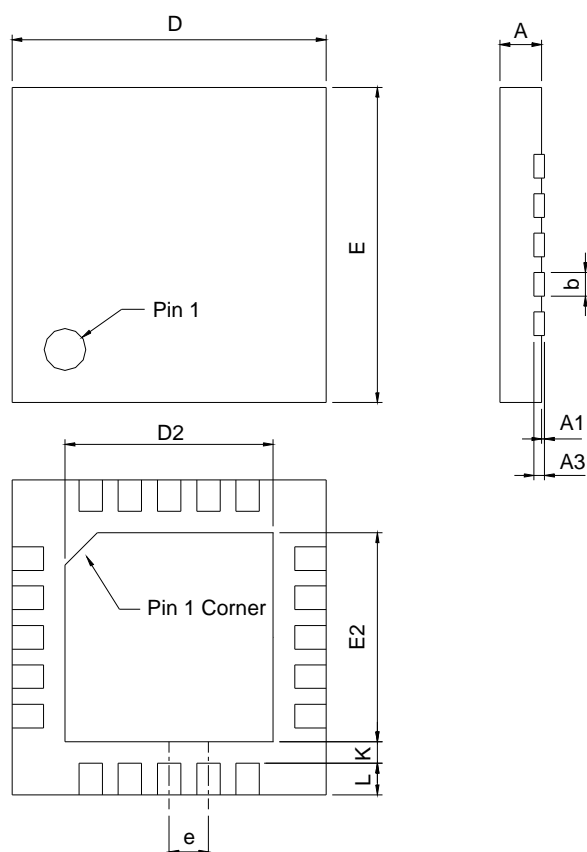
SSOP-24



SYMBOL	SSOP-24 (236mil)			
	MILLIMETERS		INCHES	
	MIN.	MAX.	MIN.	MAX.
A		1.90		0.075
A1	0.05	0.15	0.002	0.006
A2	1.30	1.70	0.051	0.067
b	0.30	0.52	0.012	0.020
c	0.15	0.27	0.004	0.011
D	12.80	13.20	0.504	0.520
E	7.70	8.30	0.303	0.327
E1	5.80	6.20	0.228	0.244
e	1.00 BSC		0.040 BSC	
L	0.40	1.27	0.016	0.050
↑	0°	10°	0°	10°

Package Information

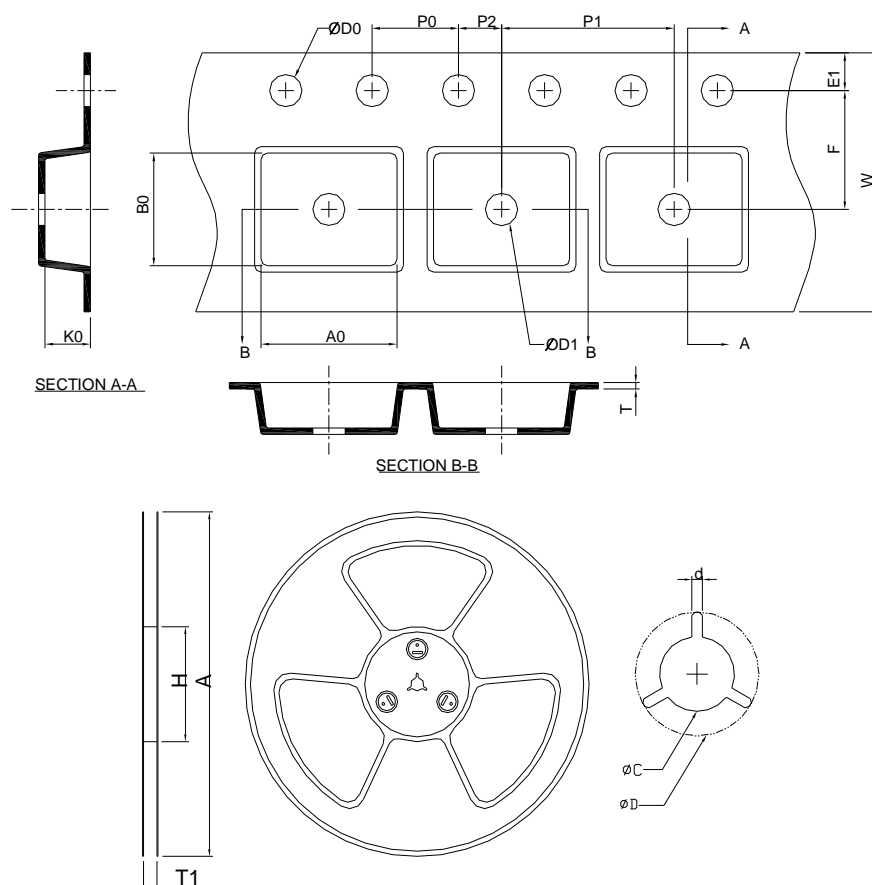
QFN4x4-20A



SYMBOL	QFN4x4-20A			
	MILLIMETERS		INCHES	
	MIN.	MAX.	MIN.	MAX.
A	0.80	1.00	0.031	0.039
A1	0.00	0.05	0.000	0.002
A3	0.20 REF		0.008 REF	
b	0.18	0.30	0.008	0.012
D	3.90	4.10	0.154	0.161
D2	2.00	2.50	0.079	0.098
E	3.90	4.10	0.154	0.161
E2	2.00	2.50	0.079	0.098
e	0.50 BSC		0.020 BSC	
L	0.35	0.45	0.014	0.018
K	0.20		0.008	

Note : 1. Followed from JEDEC MO-220 VGGD-5.

Carrier Tape & Reel Dimensions



Application	A	H	T1	C	d	D	W	E1	F
SSOP-24	330±2.00	50MIN	16.40+2.00 -0.00	13.0+0.50 -0.20	1.5MIN	20.2MIN	16.0±0.30	1.75±0.10	7.5±0.10
	P0	P1	P2	D0	D1	T	A0	B0	K0
	4.0±0.10	8.0±0.10	2.0±0.10	1.5+0.10 -0.00	1.5MIN	0.60+0.00 -0.40	6.40±0.20	9.00±0.20	2.10±0.20
Application	A	H	T1	C	d	D	W	E1	F
QFN4x4-20A	330.0±2.00	50 MIN.	12.4+2.00 -0.00	13.0+0.50 -0.20	1.5 MIN.	20.2 MIN.	12.0±0.30	1.75±0.10	5.5±0.05
	P0	P1	P2	D0	D1	T	A0	B0	K0
	4.0±0.10	8.0±0.10	2.0±0.05	1.5+0.10 -0.00	1.5 MIN.	0.6+0.00 -0.40	4.30±0.20	4.30±0.20	1.30±0.20

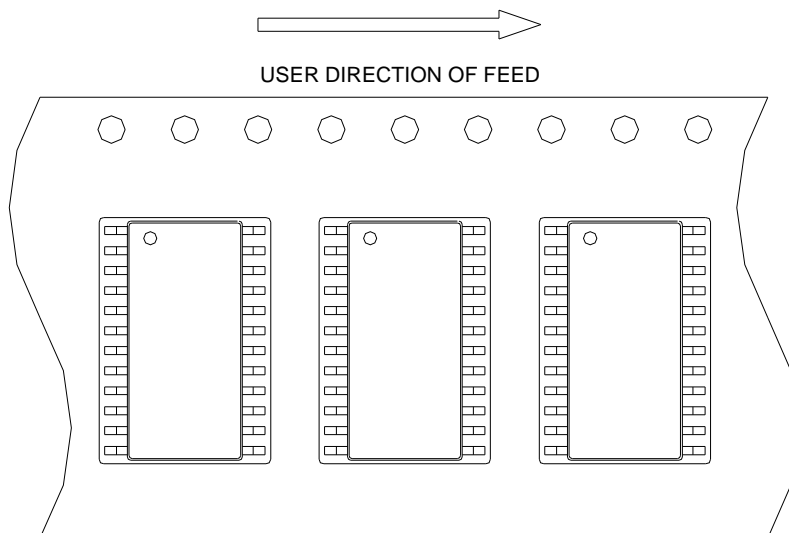
(mm)

Devices Per Unit

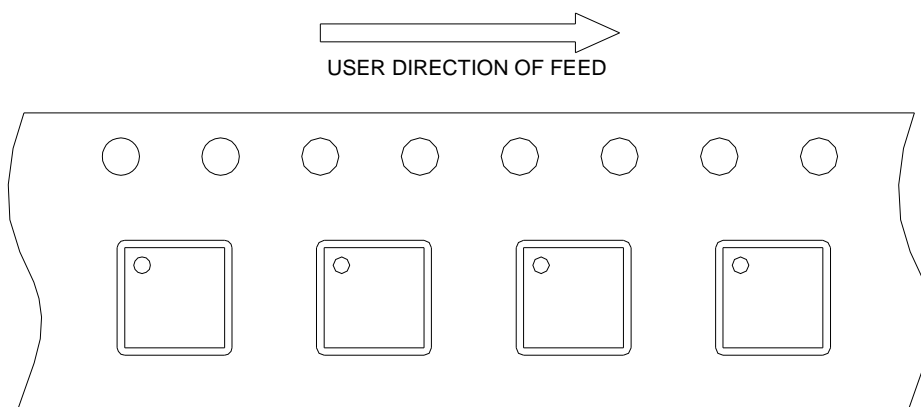
Application	Unit	Quantity
SSOP-24	Tape & Real	2500
QFN4x4-20A	Tape & Real	3000

Taping Direction Information

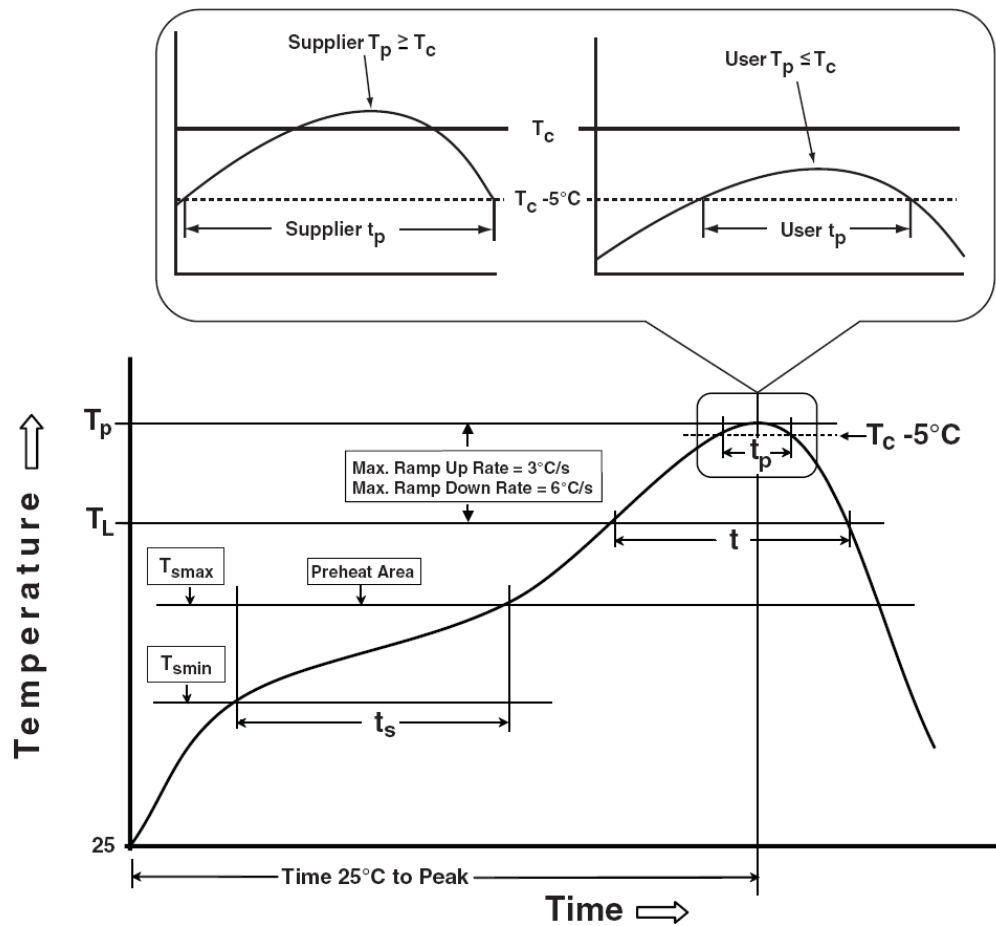
SSOP-24



QFN4x4-20A



Classification Profile



Classification Reflow Profiles

Profile Feature	Sn-Pb Eutectic Assembly	Pb-Free Assembly
Preheat & Soak Temperature min (T_{smin}) Temperature max (T_{smax}) Time (T_{smin} to T_{smax}) (t_s)	100 °C 150 °C 60-120 seconds	150 °C 200 °C 60-120 seconds
Average ramp-up rate (T_{smax} to T_p)	3 °C/second max.	3°C/second max.
Liquidous temperature (T_L) Time at liquidous (t_L)	183 °C 60-150 seconds	217 °C 60-150 seconds
Peak package body Temperature (T_p)*	See Classification Temp in table 1	See Classification Temp in table 2
Time (t_p)** within 5°C of the specified classification temperature (T_c)	20** seconds	30** seconds
Average ramp-down rate (T_p to T_{smax})	6 °C/second max.	6 °C/second max.
Time 25°C to peak temperature	6 minutes max.	8 minutes max.
* Tolerance for peak profile Temperature (T_p) is defined as a supplier minimum and a user maximum. ** Tolerance for time at peak profile temperature (t_p) is defined as a supplier minimum and a user maximum.		

Table 1. SnPb Eutectic Process – Classification Temperatures (T_c)

Package Thickness	Volume mm ³ <350	Volume mm ³ ≥350
<2.5 mm	235 °C	220 °C
≥2.5 mm	220 °C	220 °C

Table 2. Pb-free Process – Classification Temperatures (T_c)

Package Thickness	Volume mm ³ <350	Volume mm ³ 350-2000	Volume mm ³ >2000
<1.6 mm	260 °C	260 °C	260 °C
1.6 mm – 2.5 mm	260 °C	250 °C	245 °C
≥2.5 mm	250 °C	245 °C	245 °C

Reliability Test Program

Test item	Method	Description
SOLDERABILITY	JESD-22, B102	5 Sec, 245°C
HOLT	JESD-22, A108	1000 Hrs, Bias @ $T_j=125^{\circ}\text{C}$
PCT	JESD-22, A102	168 Hrs, 100%RH, 2atm, 121°C
TCT	JESD-22, A104	500 Cycles, -65°C~150°C
HBM	MIL-STD-883-3015.7	VHBM ≥ 2KV
MM	JESD-22, A115	VMM ≥ 200V
Latch-Up	JESD 78	10ms, $1_{tr} \geq 100\text{mA}$

Customer Service

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